

2814



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appln. Of: HIROAKI YOKOYAMA  
Serial No.: 08/992,767  
Filed: December 17, 1997  
For: CONTACT STRUCTURE IN SEMICONDUCTOR ...  
Group: 2814  
Examiner: D. Wille

DOCKET:  
NEC-19654 CON

The Honorable Commissioner of Patents & Trademarks  
Washington, D.C. 20231

*19# / amt E  
4/20/01  
R. Brown*

AMENDMENT D

Dear Sir:

This amendment is being filed in response to the Official Action mailed January 8, 2001. Please amend the application as follows:

IN THE CLAIMS:

~~Kindly~~ cancel claims 1 and 3-10, without prejudice.

Please add new claims 11-28 reading as follows:

11. A semiconductor device including both a large-diameter contact hole and a small-diameter contact hole formed to penetrate through an insulator film formed on a conductive portion to reach said conductive portion, each of said large-diameter contact hole and said small-diameter contact hole having a constant-diameter portion formed on a lower portion thereof, and a funnel-shaped portion formed on an upper

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